## Study of BaGe<sub>5</sub> by manual electron-diffraction tomography

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The novel tool electron-diffraction tomography [1] was used for a single-crystal structure study of BaGe<sub>5</sub> with unit cell parameters a = 10.7242(7) Å, b = 9.2873(8) Å, c = 14.7905(11) Å (refined from X-ray powder diffraction data) [2] and space group *Pmna* (previous electron diffraction study) [3]. The BaGe<sub>5</sub> phase was obtained as microcrystalline material (layered crystallites, about  $6 - 15 \mu m$  length, about  $0.5 - 3 \mu m$  thickness, Fig. 1 *left*) by decomposition of the high-temperature Ba<sub>8</sub>Ge<sub>43</sub> clathrate-I (stable at 770°C to 810 °C) after annealing at 460 °C [2]. The first attempt to solve its crystal structure from precession electron diffraction data (precession semi-angle 1°) failed [3]. Although, in the meantime the BaGe<sub>5</sub> to test the manual electron-diffraction tomography technique and learn about all the features and difficulties of the method.

Conventional transmission electron microscopy and manually collected diffraction tomography were performed on a FEI TECNAI 10 (100 KV) microscope, equipped with a 2k CCD camera (TemCam-F224HD from TVIPS). The selected area diffraction (SAED) mode was used for data collection. The aperture area had at the image plane a size of about 450 nm. A small crystal (Fig. 1 *right*) on the holey carbon-coated TEM support grid was selected for data acquisition (without beam precession). The tilt sequence at steps of 1° was performed manually in a total tilt range of 130° (± 65°) using a standard double-tilt holder from GATAN. The collected series data was stored as a set of files in TIF format and converted into MRC stacks, which were further processed using the ADT3D software package [1] for a reconstruction of the diffraction volume. After indexing the 3D-spots in the reciprocal-space lattice of BaGe<sub>5</sub>, their intensities were integrated and stored as standard *hkl*-files (1412 reflections; 454 unique reflections). In Fig 2, two projections (along *a* and *b* axes) of the three-dimensional reconstructed reciprocal-space diffraction volume of BaGe<sub>5</sub> are illustrated. The unit cell parameters resulting from electron-diffraction tomography were *a* = 10.762 Å, *b* = 9.270 Å, *c* = 14.919 Å,  $\alpha$  = 89.53°,  $\beta$  = 89.77°,  $\gamma$  = 89.72°.

Structure solution was achieved by direct methods using SIR2008 software [5]. All the atomic positions of BaGe<sub>5</sub> structure were obtained by direct methods and were refined with the SHELXL software [6]. The final *R*-value was relative large ( $R_1 = 0.247$ ; 423 reflections, 40 refined parameters) but reasonable for electron diffraction data without corrections for absorption or residual dynamical effects. The Ba–Ge (3.15 – 4.10 Å) and Ge–Ge (2.38 – 2.66 Å) distances were similar to those obtained by X-ray powder diffractometry methods.

Although, several details of the crystal structure were already discussed before [2, 4], we can mention here that the semiconductor BaGe<sub>5</sub> discloses a partially disordered structure related to both clathrate types I and II. It contains germanium vacancies arranged in layers parallel to (010) plane, appearing as a collapsed clathrate-II structure or as a reconstructed clathrate-I realized by crystallographic shear [2].

In summary, we were able to solve the crystal structure of BaGe<sub>5</sub> using *hkl*-intensity data acquired by manual electron-diffraction tomography. This success opens new perspectives for our future investigations on micro- and nano-structured intermetallic and other compounds.

## References

- [1] U Kolb et al., Cryst. Res. Technol. 46 (2011) p. 542.
- [2] W Carrillo-Cabrera, Z. Kristallogr. 236 (2011) p. 619.
- [3] W Carrillo-Cabrera, MC2009 Conference Proceedings 1 (2009) p. 275.
- [4] U Aydemir et al., J. Am. Chem. Soc. **132** (2010) p. 10984.
- [5] MC Burla et al., J. Appl. Crystallogr. 40 (2007) p. 609.
- [6] GM Sheldrick, Acta Crystallogr. A64 (2008) p. 112.



*Figure 1.* (left) Bright field TEM image showing elongated crystallites of BaGe<sub>5</sub>, several of them with stacking faults. (right) Crystal fragment (200x190x90 nm) used for the electron-diffraction tomography study.



*Figure 2.* Projections of the reciprocal volume along [100] (left) and [010] (right) directions. It can be recognized that the spot intensity distribution has symmetry revealing a kinematical character.